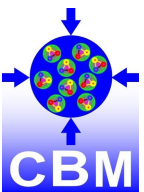


The Silicon Tracking System of the Compressed Baryonic Matter (CBM) Experiment at FAIR

Hans Rudolf Schmidt, for the CBM Collaboration
University of Tübingen

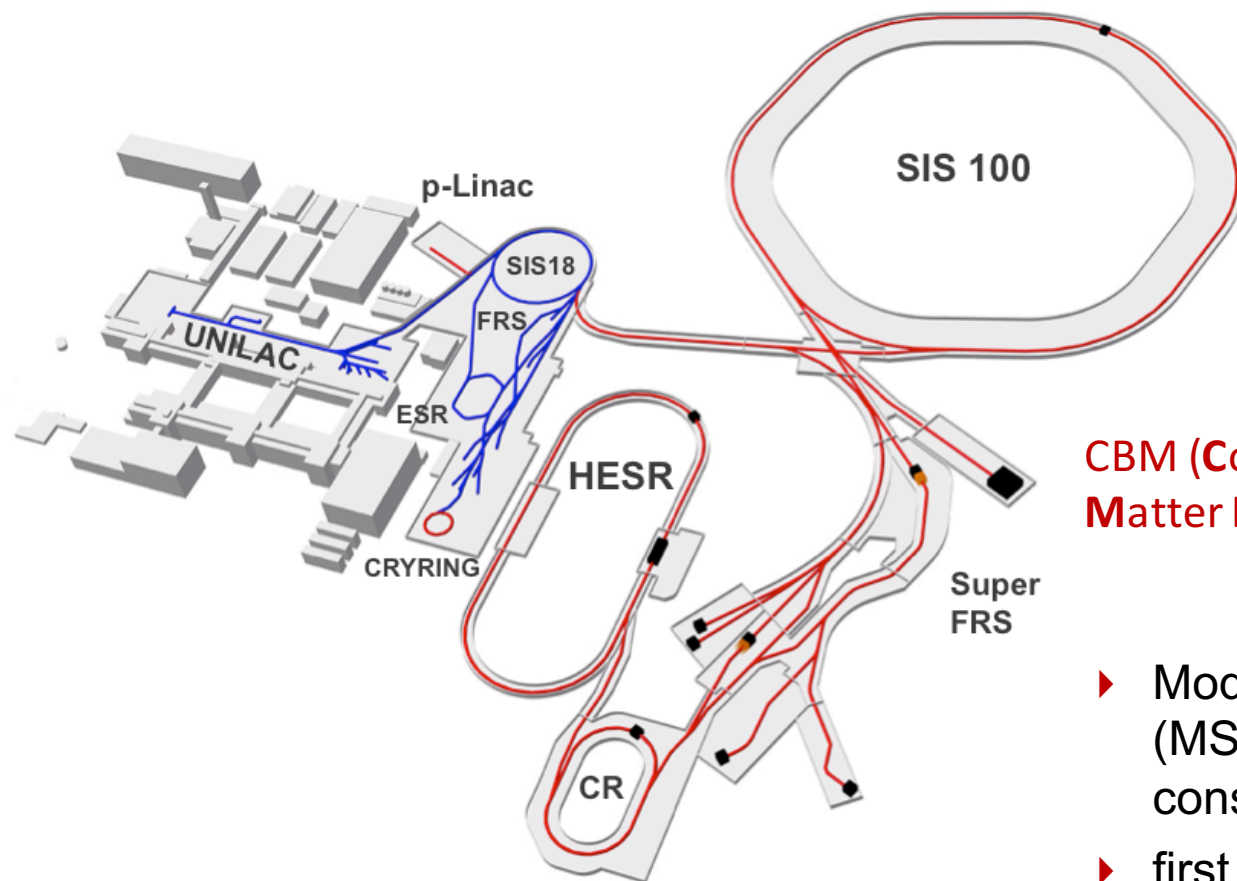


EBERHARD KARLS
UNIVERSITÄT
TÜBINGEN



Frontier Detectors for Frontier Physics
14th Pisa Meeting on Advanced Detectors

May 27 – June 2 2018 • La Biodola, Isola d'Elba (Italy)



CBM (**C**ompressed **B**aryonic
Matter Experiment)

- ▶ Modularized Start Version (MSV) of FAIR currently under construction
- ▶ first beams (p,..., U) expected 2024
- ▶ $E_{\text{beam}} = 11 - 29 \text{ AGeV}$



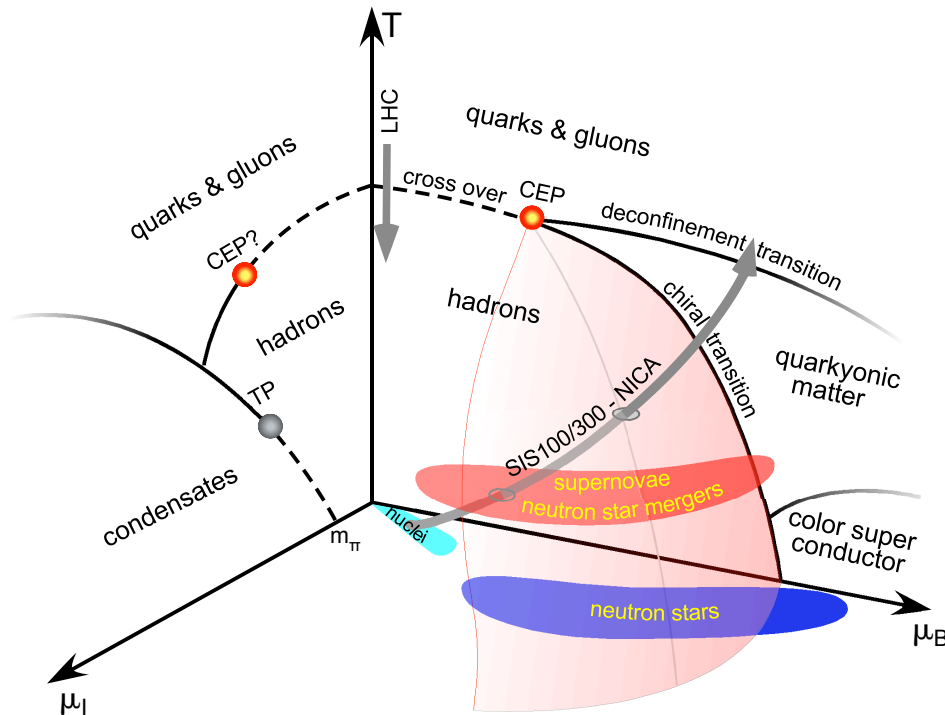
► areal view



- excavation of the SIS100 tunnel

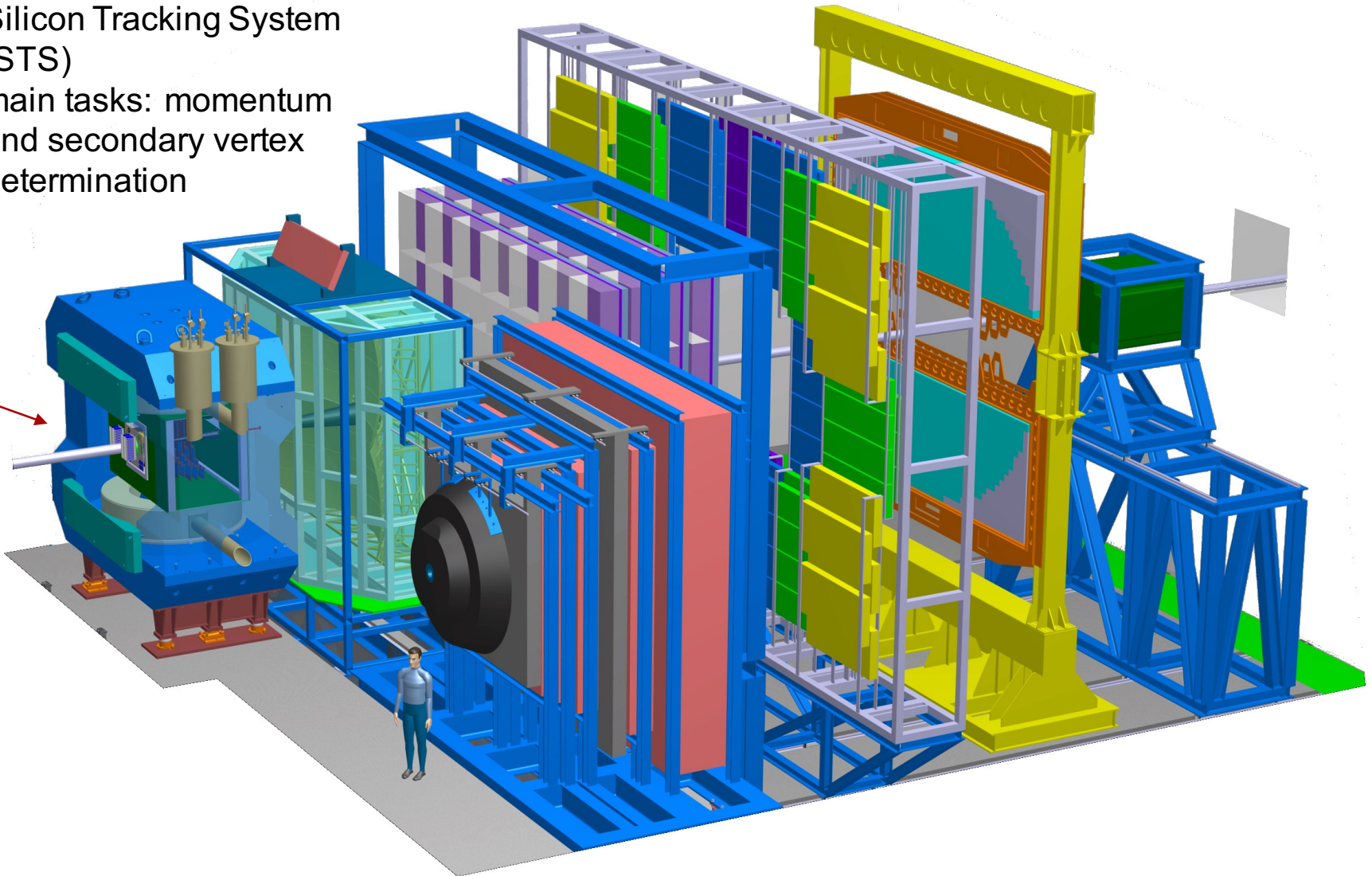


- excavation of the SIS100 tunnel (May 2018)

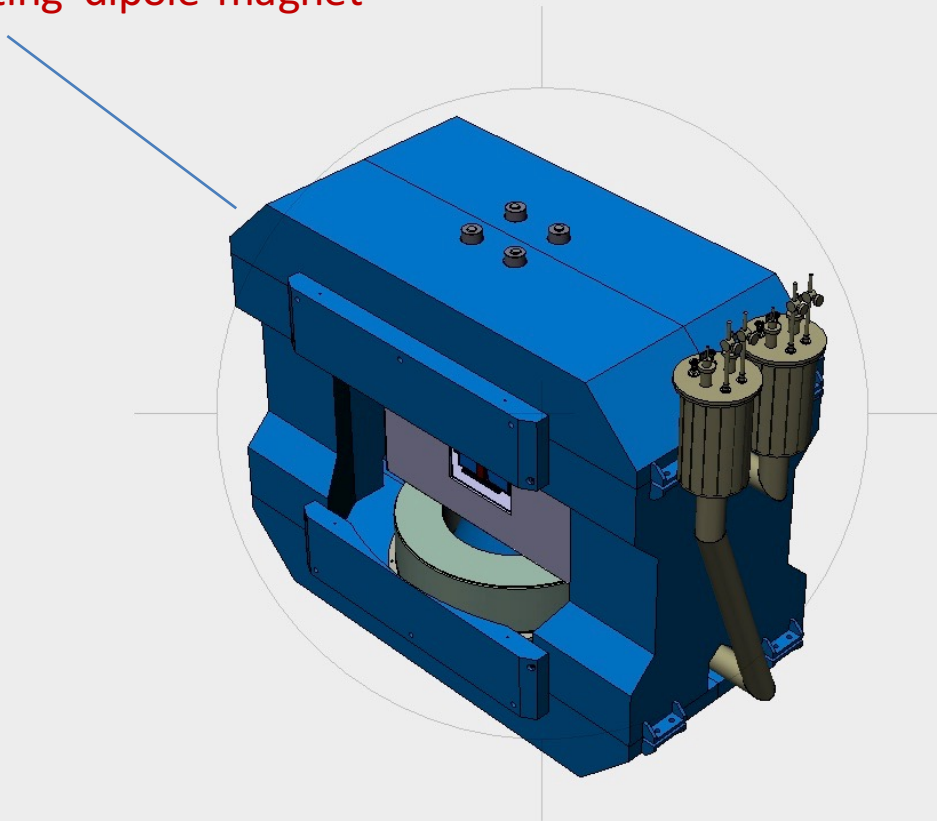


- ▶ Exploration of the QCD phase diagram at high μ_B and moderate temperatures
 - ▶ de-confinement and chiral transitions
 - ▶ equation-of-state relevant for neutron stars and neutron star mergers
 - ▶ utilizing **rare** probes: dilepton, multi-strangeness
- ▶ Note: this is generally **low- p_t physics**
- ▶ CBM sub-detectors must be capable to measure at **rel. low momentum** but at **high interaction rates ($\sim 10 \text{ Mhz}$)**

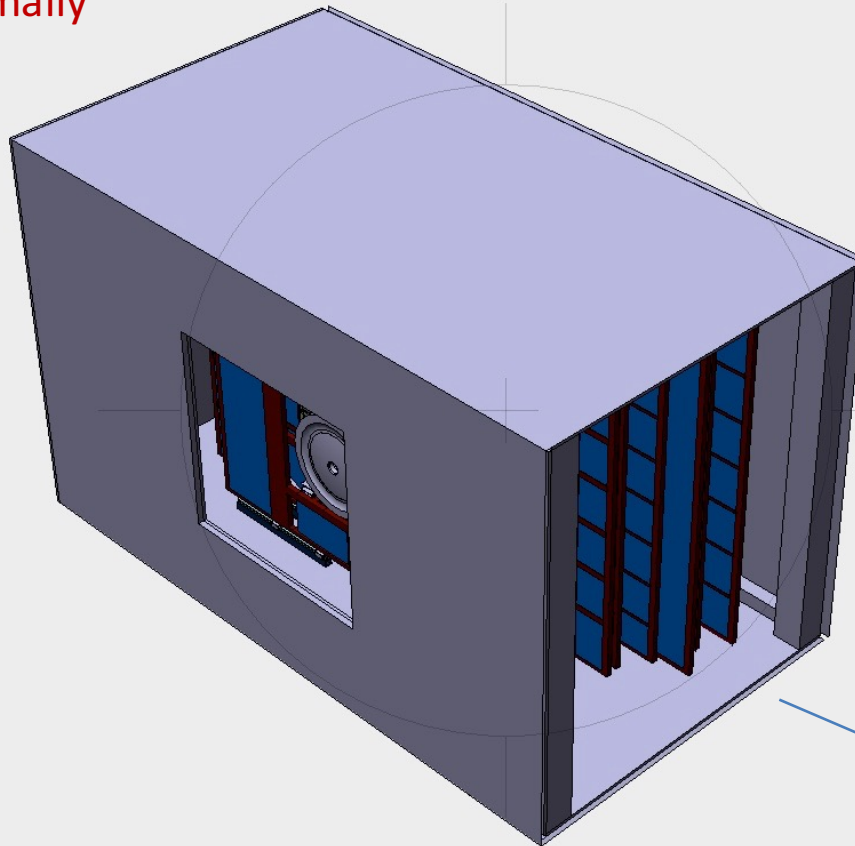
- ▶ Silicon Tracking System (STS)
- ▶ main tasks: momentum and secondary vertex determination



1 Tm superconducting dipole magnet

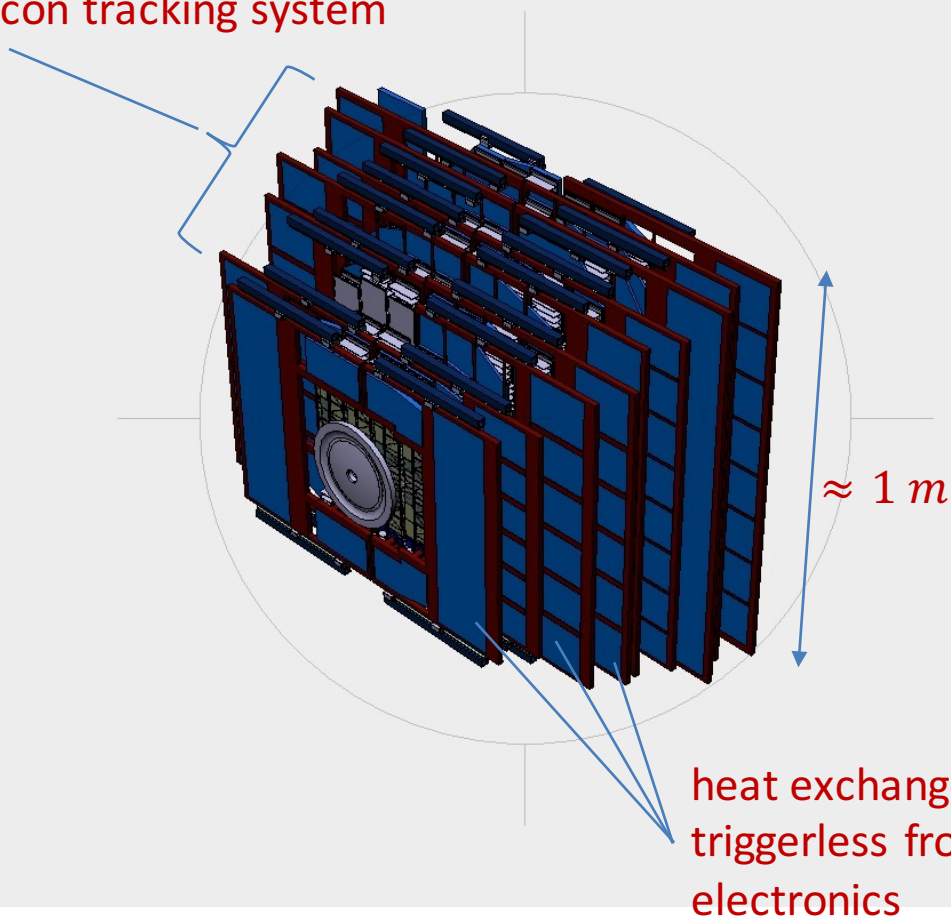


inside magnet: thermally
insulating box

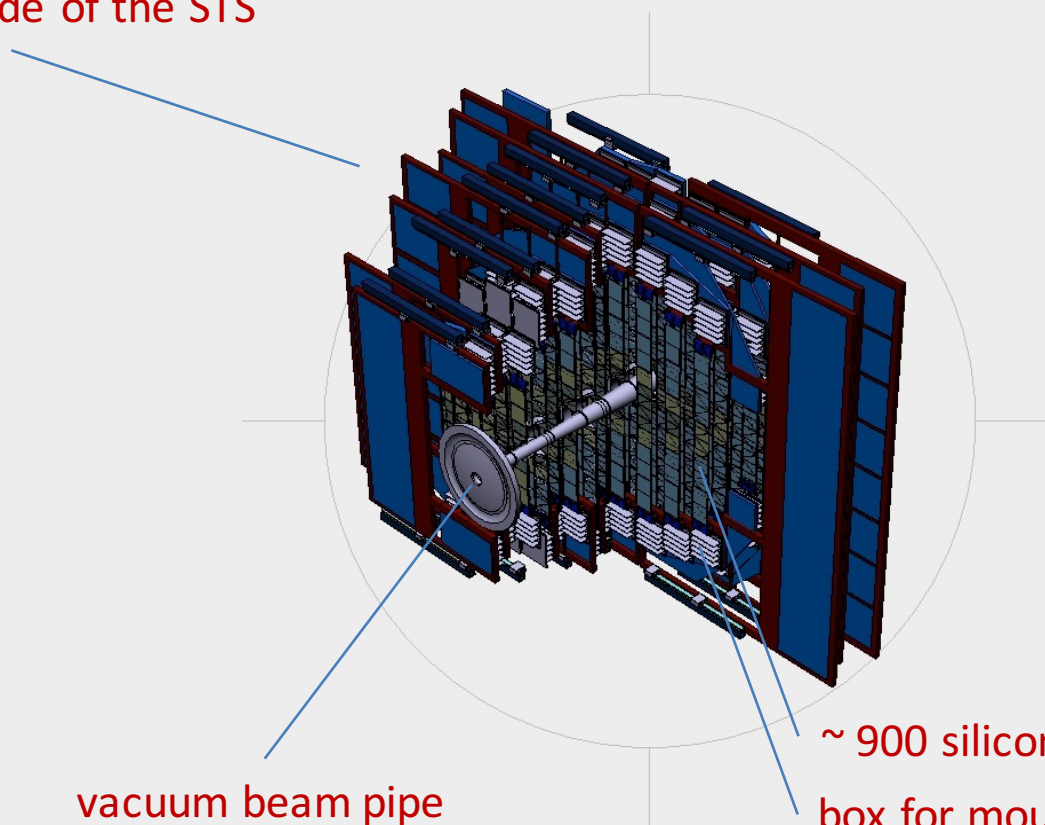


side walls removable for
maintenance

8 stations of the silicon tracking system



cut view inside of the STS

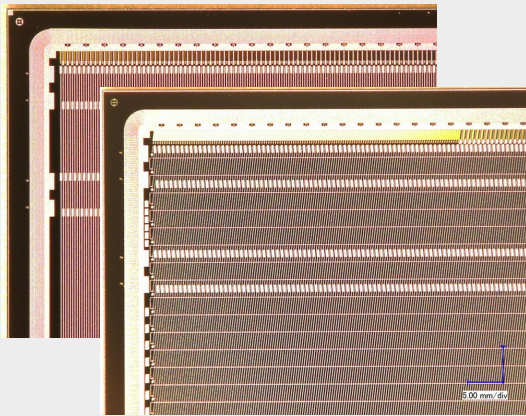


vacuum beam pipe

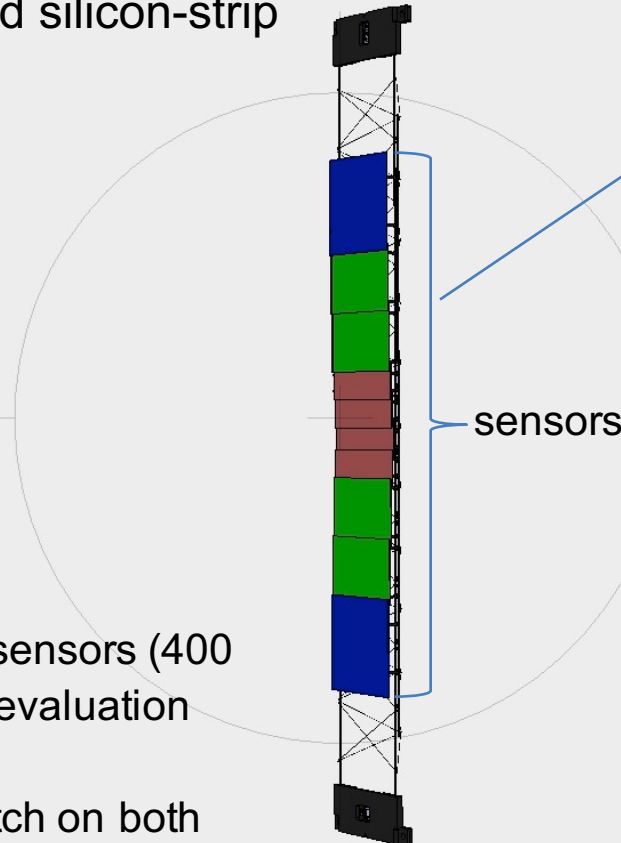
~ 900 silicon sensors on CF ladders
box for mounting front-end ASICs



sensor type: double-sided silicon-strip



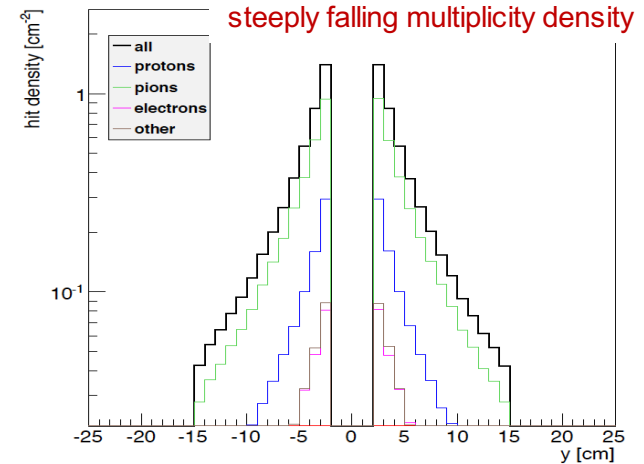
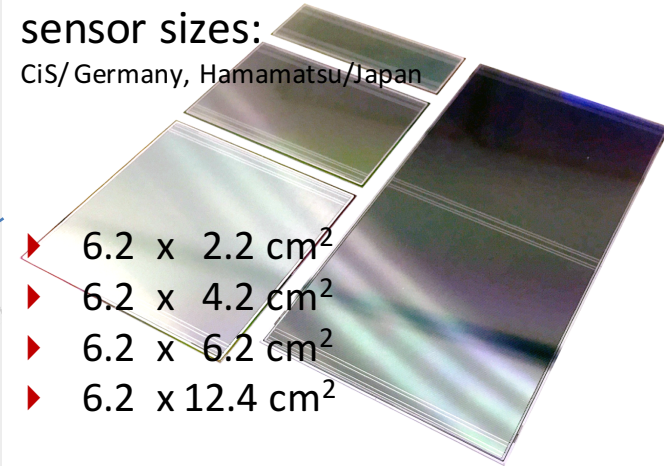
- ▶ $285/320 \pm 15 \mu\text{m}$ thick
 - ▶ impact of thicker sensors (400 or $500 \mu\text{m}$) under evaluation
- ▶ n-type silicon
- ▶ 1024 strips of $58 \mu\text{m}$ pitch on both sides
- ▶ angle front/back: $7.5^\circ/0^\circ$



sensor sizes:

CiS/ Germany, Hamamatsu/Japan

- ▶ $6.2 \times 2.2 \text{ cm}^2$
- ▶ $6.2 \times 4.2 \text{ cm}^2$
- ▶ $6.2 \times 6.2 \text{ cm}^2$
- ▶ $6.2 \times 12.4 \text{ cm}^2$



- ▶ best possible momentum resolution at low momenta

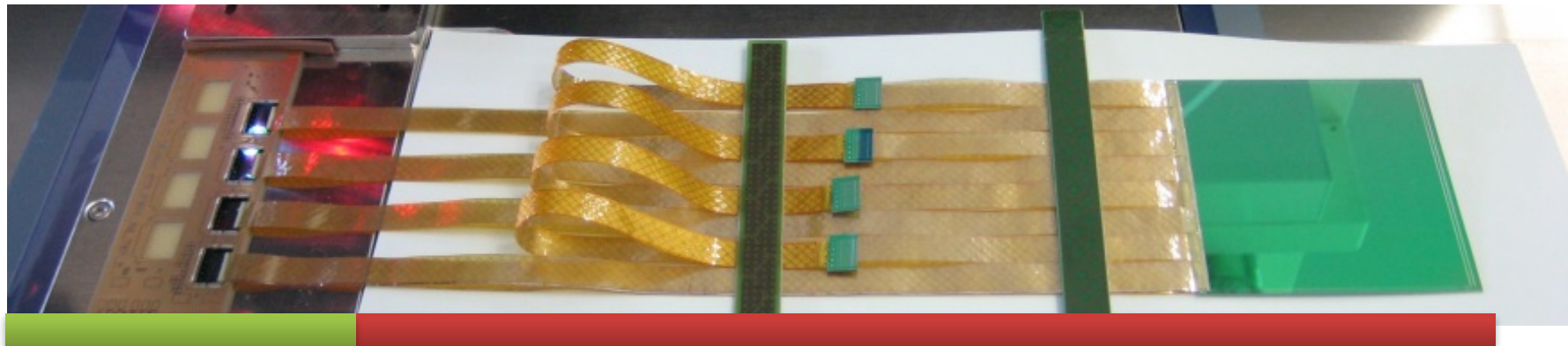
⇒ minimize multiple scattering $\Theta_m = \frac{13.6 \text{ MeV}}{\beta \cdot c \cdot p} \cdot \sqrt{\frac{X}{X_0}} \Leftrightarrow$ **minimize material budget**

- ▶ basic functional unit is a **module**, consisting of:

FEB with r/o ASICs

ultra-thin micro cables

sensor



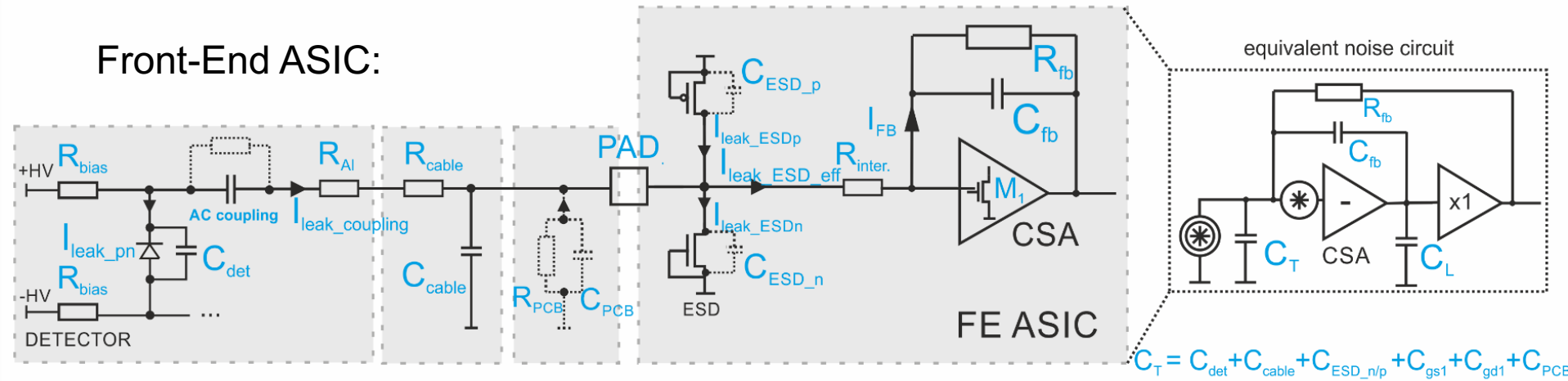
FEB outside of acceptance

inside of acceptance

- ▶ geometry/multiplicity density dictates **18** different module types!
 - ▶ different sensor, different cable, different bandwidth of r/o

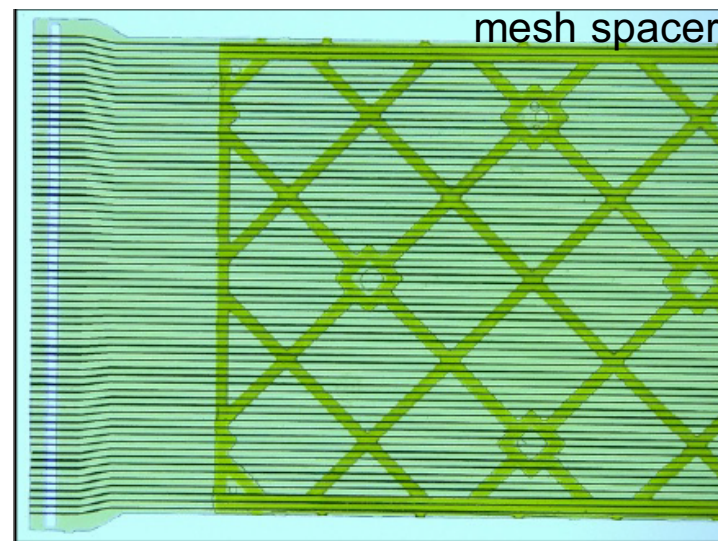
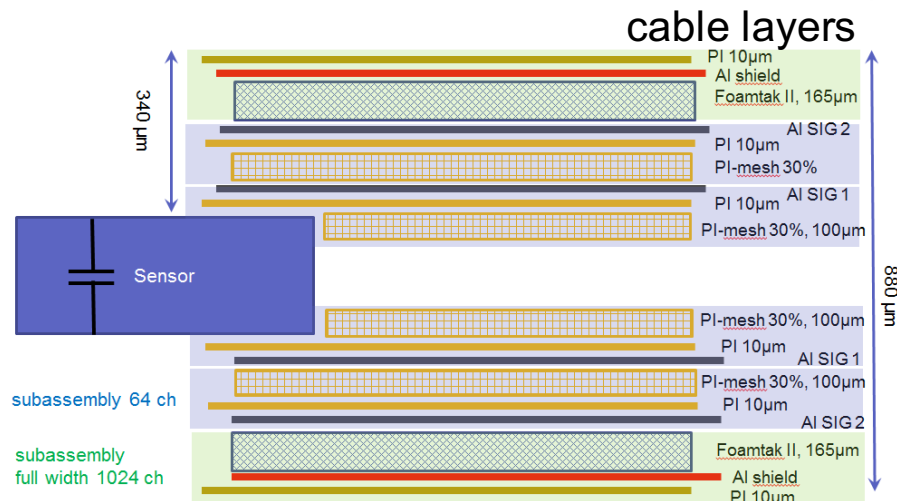
- ▶ Design goal: $ENC_{\text{total}} < 1000e \text{ RMS}$
- ▶ $ENC_{\text{FEE}} < 500e \text{ RMS}$ (complex, many contributions)

Front-End ASIC:



- ▶ Noise scales with total capacitance:
 - ▶ $C_T = C_{\text{det}} + C_{\text{cable}} + C_{\text{ESD_n/p}} + C_{\text{gs1}} + C_{\text{gd1}} + C_{\text{PCB}}$
- ⇒ careful design of μ -cables to minimize capacitance

- ▶ main design constraints: capacitance, bonding scheme, production yield
- ▶ signal layer: 64 lines - 116 μm pitch, 14 μm thick, on 10 μm polyimide
 - ▶ 32 cables/sensor
 - ▶ **mesh layer** between signal and ground layer to decrease capacitance
- ▶ alternative mounting schemes:
 - ▶ Aluminum-Polyimide technology, **tab bonding** (LTU Ltd, Kharkov, Ukraine)
 - ▶ Copper-Polyimide technology, **stud bonding** (KIT, Karlsruhe)



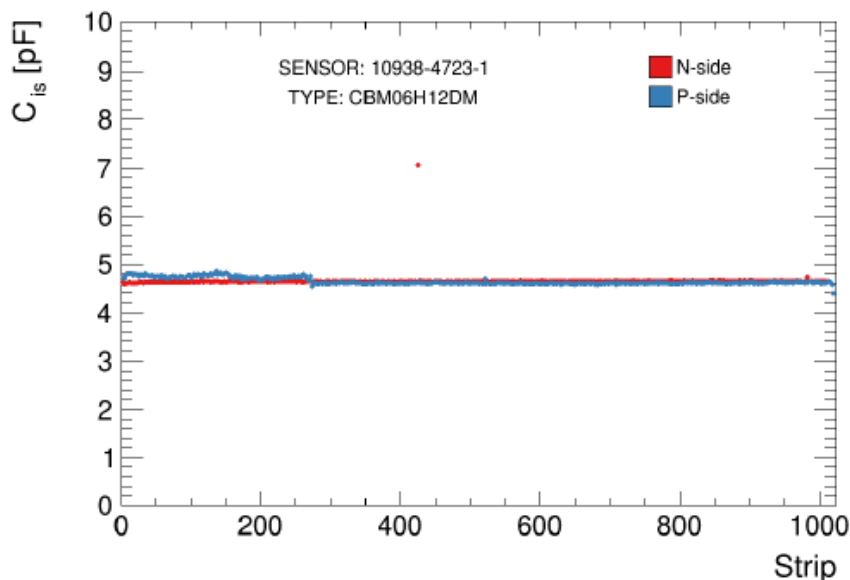
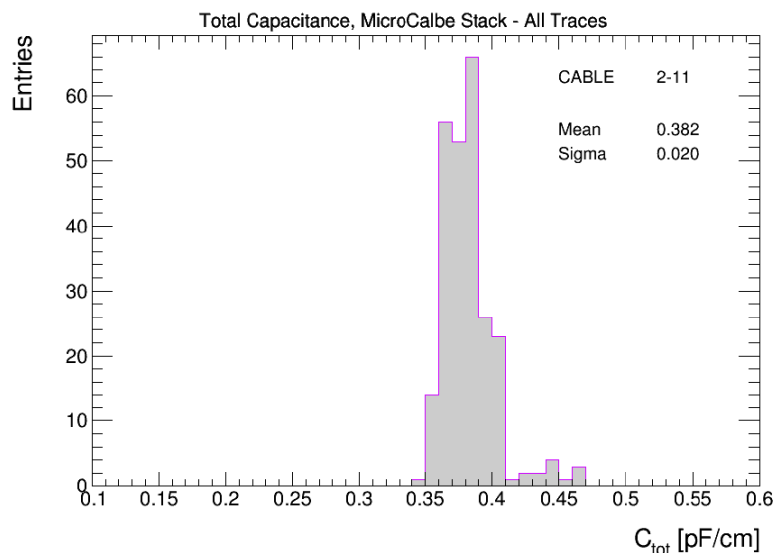
- ▶ cable total capacitance

$$C_{\text{cable}} = 0.382 \pm 0.020 \text{ pF/cm}$$

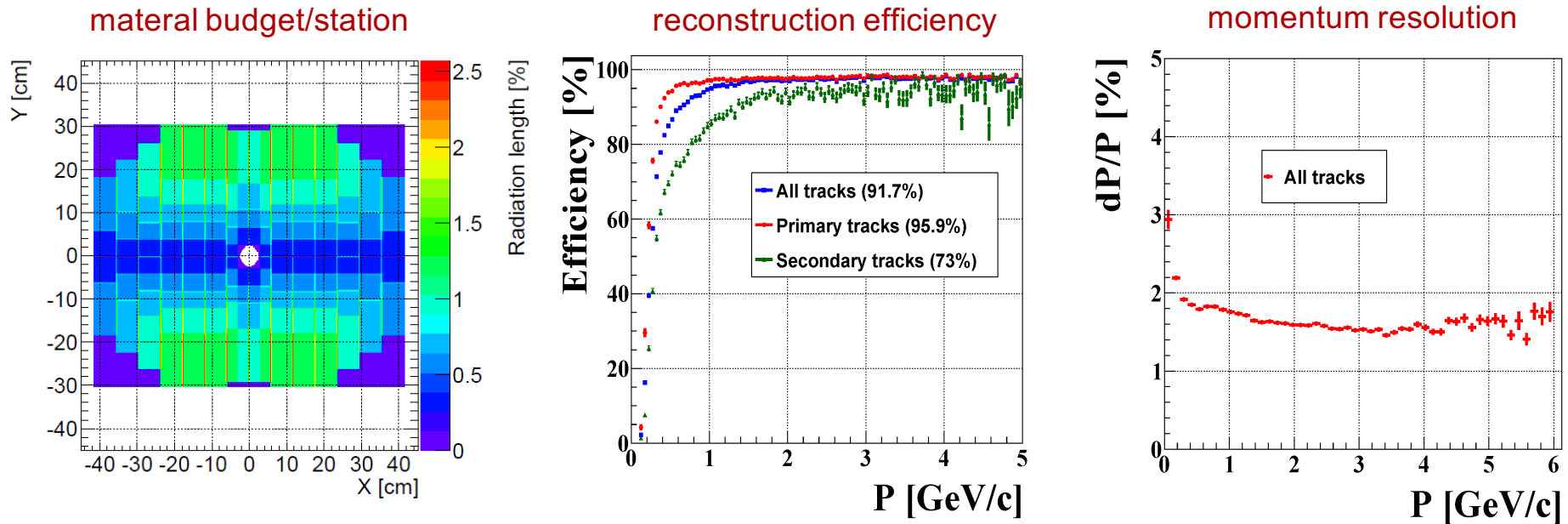
- ▶ sensor interstrip capacitance

- ▶ 12 cm sensor (Hamamatsu)

$$C_{\text{interstrip}} = 0.38 \pm 0.2 \text{ pF/cm}$$

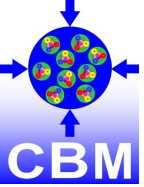


- ▶ design goal: cable capacitance/cm² should not exceed interstrip value of sensor
- ▶ cable length up to 55 cm!



► **material budget** ranges from $X/X_0 = 0.3$ (sensor only) to $X/X_0 = 1 - 1.5\%$ (sensors + cables) resulting in:

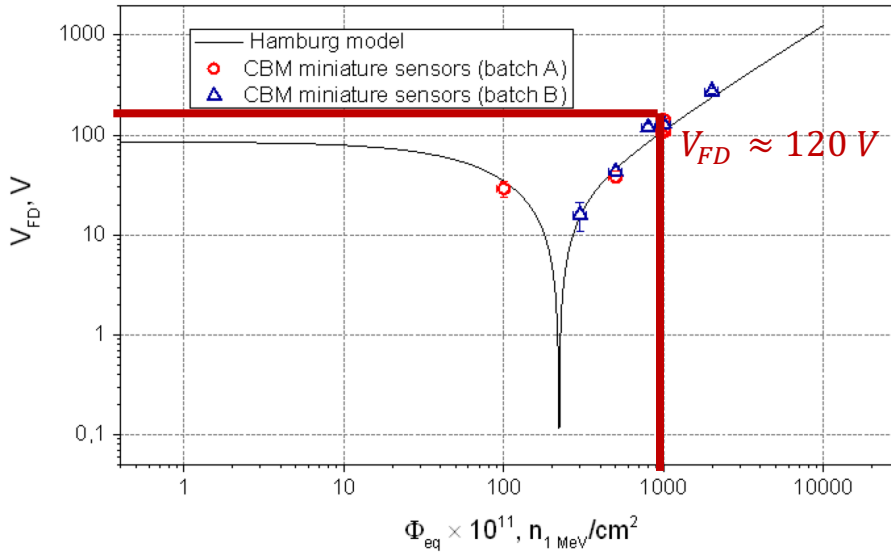
- reconstruction efficiency (simulation): $\epsilon \approx 98\%$
- momentum resolution (simulation): $\frac{\delta p}{p} \approx 1.5 - 2\%$



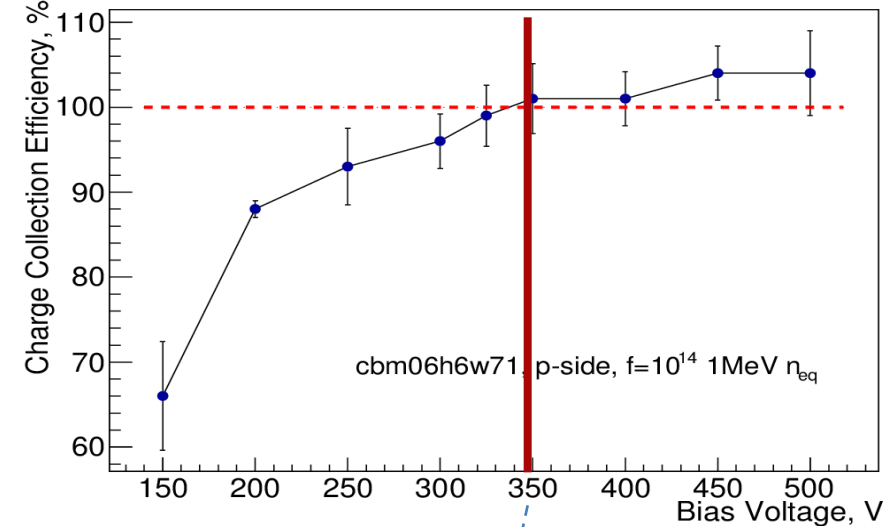
Challenges III: Radiation Tolerance



type inversion with fluence

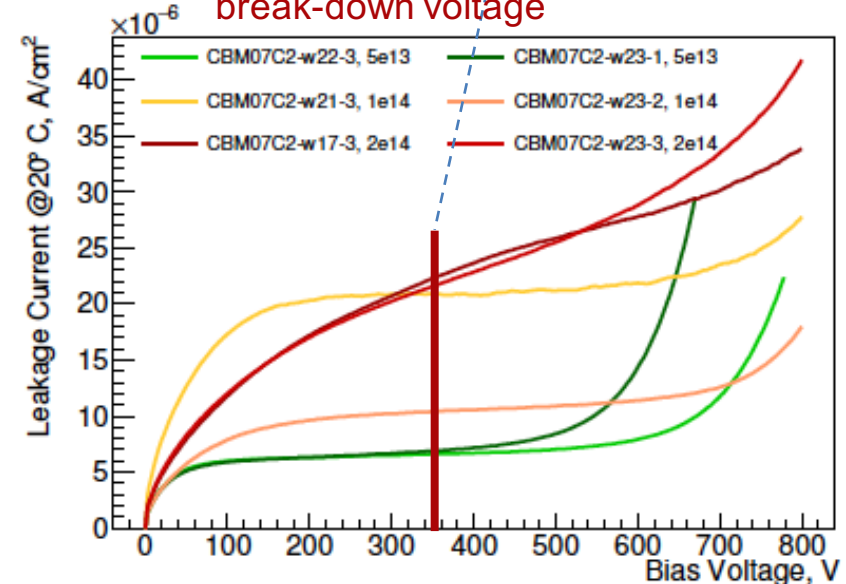


charge collection efficiency irradiated sensors

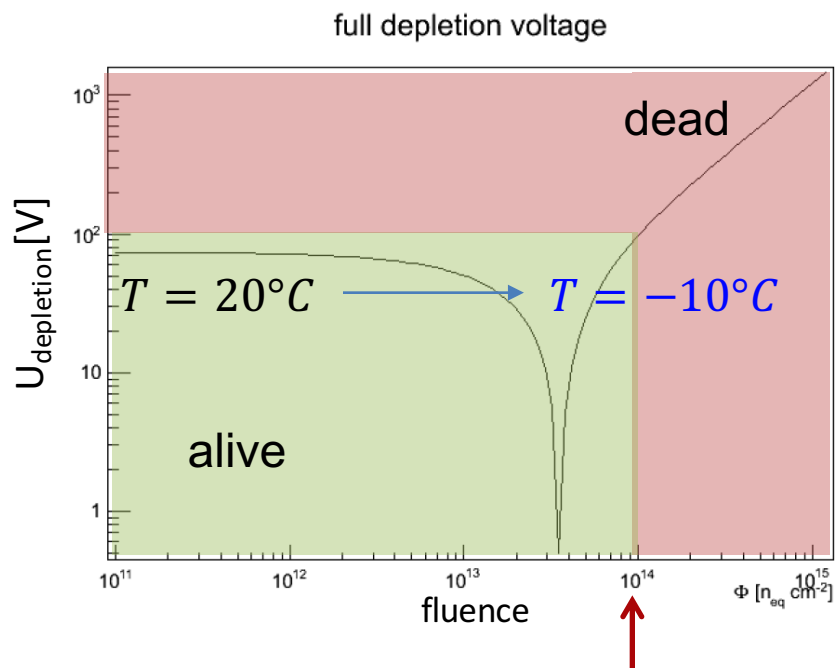


- ▶ life time fluence: $\Phi_{eq} = 10^{14} n_{1 \text{ MeV}} \text{ cm}^{-2}$
 - ▶ 5-10 month of running at 10 MHz
- ▶ corresponding full depletion voltage: $V_{FD} \approx 120 \text{ V}$
- ▶ to recover charge collection eff.: $V_{FD} > 350 \text{ V}$
- ▶ high current or breakdown essentially sets limit to the lifetime

break-down voltage



- effects in high radiation environment:



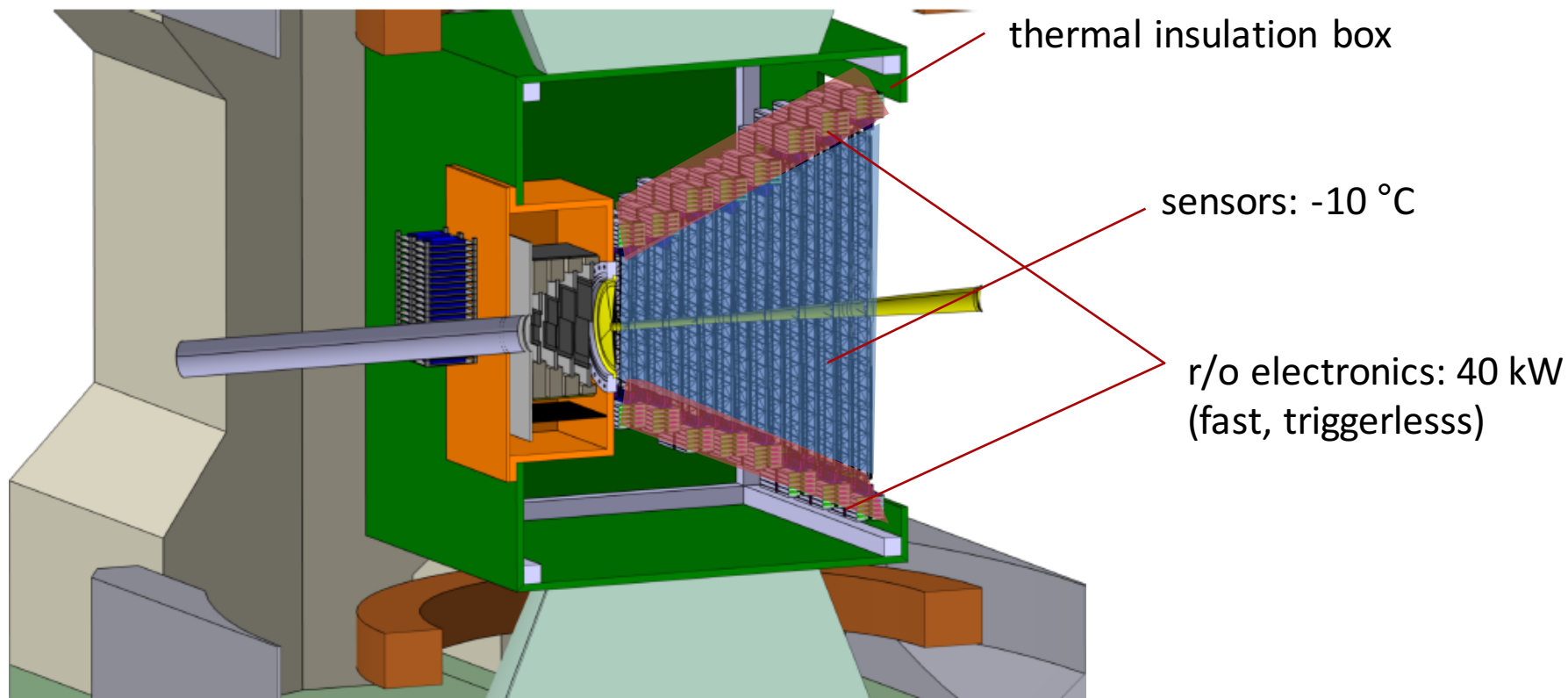
up tp 6 mW/cm² at end of life
time ($\Phi_{eq} = 10^{14}_{n_{1MeV}} \text{cm}^{-2}$)

$$I_{leak}(V, \Phi) = \alpha V \Phi$$

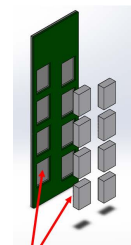
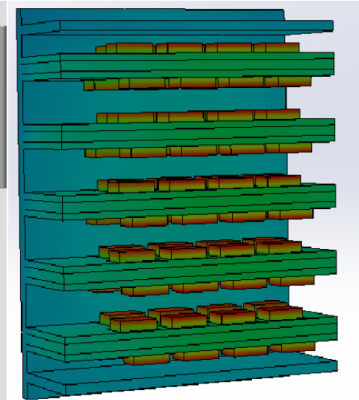
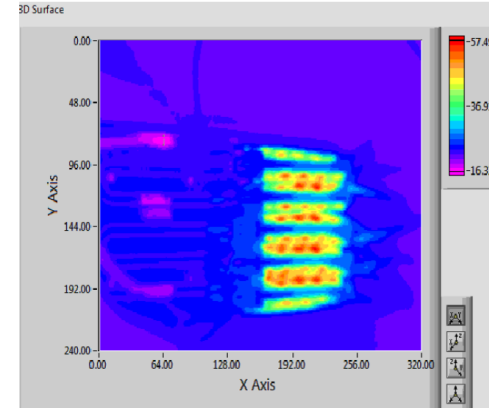
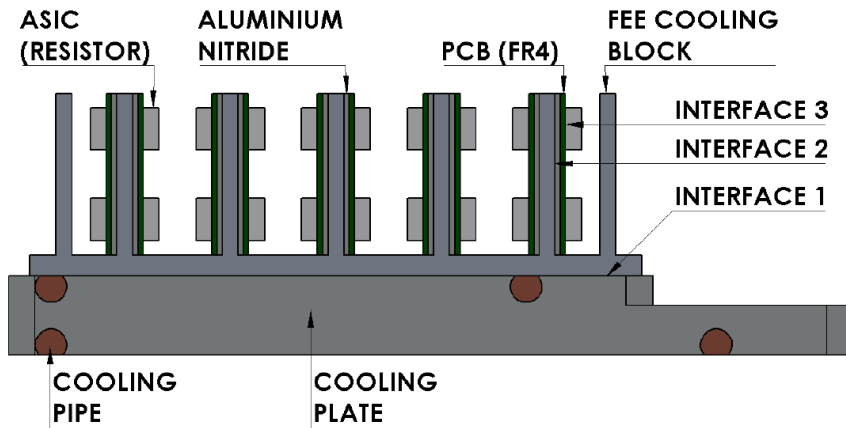
$$I_{leak}(T) = I_{leak,293} \left(\frac{T}{293} K \right)^2 \exp \left(-\frac{E_{gap}(T)}{2k_B} \right) \left(\frac{1}{T} - \frac{1}{293K} \right)$$

- leakage current increase with fluence V, Φ and temperature T
- ⇒ sensor cooling mandatory to avoid thermal runaway
- ⇒ keep sensors permanently at $T = -10^{\circ}\text{C}$

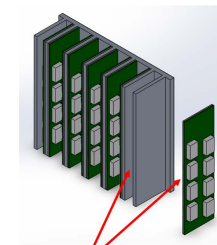
- ▶ fast readout electronics produces 40 kW thermal power within insulation volume



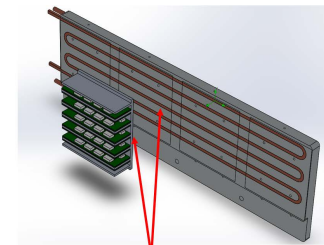
- ▶ Efficient high power CO₂ cooling system under development to neutralize 40 kW thermal power from r/o electronics!
- ▶ but: innermost sensors produce up to 6 mW/cm² – cooling by forced N₂ convection??



Interface 3:
Aluminium Nitride –
Resistors (ASICs)



Interface 2:
Aluminium Nitride –
Aluminium Fin

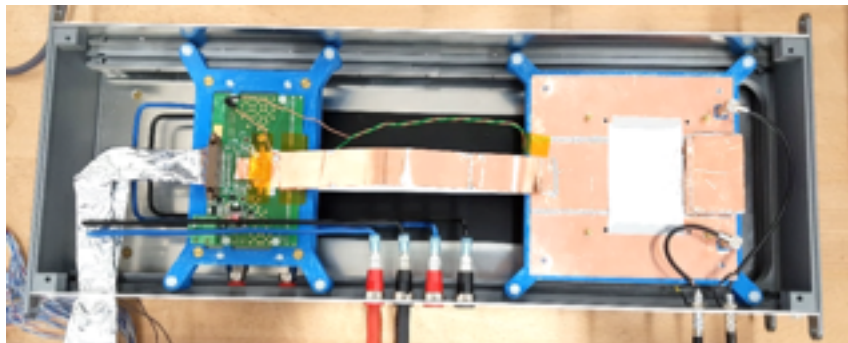


Interface 1:
FEE box – Cooling
Plate

- ▶ optimization of:
 - ▶ heat exchanger (P=120 bar)
 - ▶ thermal interfaces
- ▶ large scale cooling demonstrator

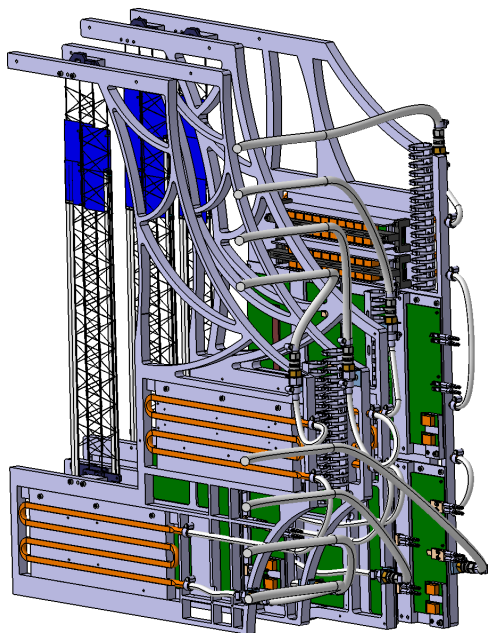
see poster by Kshitij Agarwal

single module



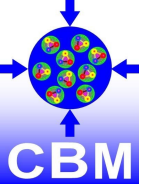
- ▶ module test at COSY, Feb. 2018
 - ▶ proton beam, 1.7 GeV/c
 - ▶ 128 channels /side read out
 - ▶ microcable 25 cm long
- ▶ design parameters verified
 - ▶ $ENC = 1090 \pm 150 \text{ e (n)}$
 - ▶ $ENC = 1350 \pm 200 \text{ e (p) (?)}$
 - ▶ **signal-to-noise: 15 ± 3**

miniSTS



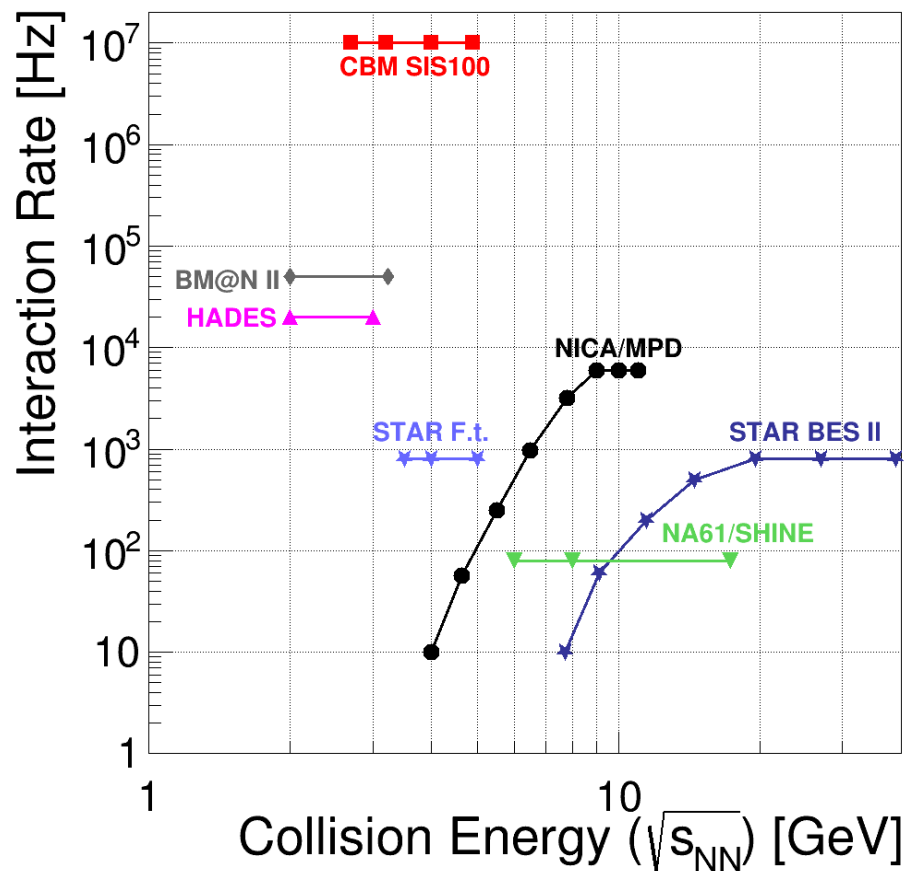
- ▶ **miniSTS** in demonstrator experiment miniCBM at GSI/SIS18 in 2018/19
 - ▶ up to 4 layers of silicon
 - ▶ full system test including streaming readout

- ▶ CBM STS design optimized wrt
 - ▶ material budget and radiation tolerance
 - ▶ sensor R&D finished
 - ▶ sophisticated QA methods developed (see poster by E. Lavrik)
 - ▶ cooling R&D ongoing
- ▶ sensor production readiness review (April 2018)
 - ▶ ready for tendering
 - ▶ sensor purchasing & module production 2019-2020
- ▶ participating laboratories
 - ▶ GSI Darmstadt (QA, assembly, integration)
 - ▶ JINR Dubna (QA, assembly)
 - ▶ University of Tübingen (QA, cooling)
 - ▶ KIT Karlsruhe (cables, assembly)
 - ▶ AGH, Cracow (readout ASICs)
 - ▶ JU, Cracow (readout)
 - ▶ WUT, Warsaw (readout)



backup





- ▶ utilizing rare probes requires high luminosity (**high interaction rates**)
- ▶ $R_{\text{int}} = 10$ MHz, several OoM higher than at colliders at comparable collision energies
- ▶ CBM sub-detectors must be capable to measure at **rel. low momentum** but at **high rates**

- ▶ Mutual interest by CBM groups from Germany and Russia to install, commission and use 4 CBM-like Silicon Tracking Stations in BM@N in 2019 – 2021
- ▶ Au beams up to 4.5 GeV/u

